E6312: Problem Set 1

Miles Sherman

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1 Problem 1

1.0.1 Part 1

In this simulation I aimed to plot I_{DS} vs. V_{GS} for my nMOS at $V_{DS} = 0.9$ V. To do this I set up a DC simulation where I swept V_{GS} from 0V to 2V while plotting the current at the drain (I_{DS}) as my output. I chose this range because it shows the full progression of the device from weak inversion to strong inversion. My plotted output can be seen in Figure 1.

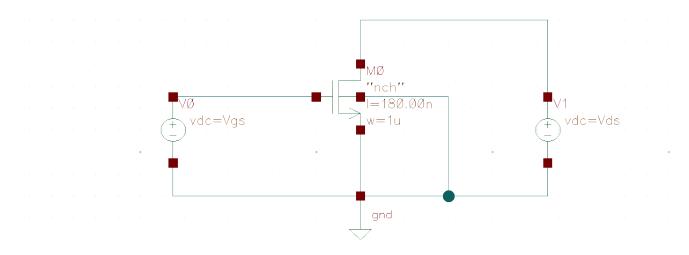


Figure 1: I_{DS} vs. V_{GS} for an nMOS at $V_{DS}=0.9\mathrm{V}$